8-bit dual supply translating transceiver; open drain; auto direction sensing

Rev. 1.1 — 13 April 2021

Product data sheet

1 General description

The NTS0308E is an 8-bit, dual supply translating transceiver family with auto direction sensing, that enables bidirectional voltage level translation. It features eight 1-bit input-output ports (A and B), one output enable input (OE) and two supply pins (V_{CC(A)} and V_{CC(B)}). V_{CC(A)} can be supplied at any voltage between 0.95 V and 3.6 V. V_{CC(B)} can be supplied at any voltage between 1.65 V and 5.5 V. This flexibility makes the device suitable for translating between any of the voltage nodes (0.95 V, 1.2 V, 1.8 V, 2.5 V, 3.3 V and 5.0 V). V_{CC(A)} must be \leq V_{CC(B)} to ensure proper operation.

Pins A and OE are referenced to $V_{CC(A)}$ and pin B is referenced to $V_{CC(B)}$. A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state.

2 Features and benefits

- Wide supply voltage range:
 - $V_{CC(A)}$: 0.95 V to 3.6 V and $V_{CC(B)}$: 1.65 V to 5.5 V; $V_{CC(A)}$ must be $\leq V_{CC(B)}$
- No power-sequencing required
- Maximum data rate
 - Open-drain: 2 Mbps
 - Push-pull: 20 Mbps
- Longer one-shot pulse for driving larger capacitive loads with much reduced ringing and overshoot
- A-side and OE inputs accept voltages up to 3.6 V and are 3.6 V tolerant
- · B-side inputs accept voltages up to 5.5 V and are 5.5 V tolerant
- ESD protection:
 - IEC 61000-4-2 Class 4, 8 kV contact for B-side port
 - HBM JESD22-A114E Class 2 exceeds 2000 V for both ports
 - CDM JESD22-C101E exceeds 1000 V for both ports
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Package options: TSSOP20
- Specified from -40 °C to +125 °C

3 Applications

- I²C/SMBus, UART
- GPIO



4 Ordering information

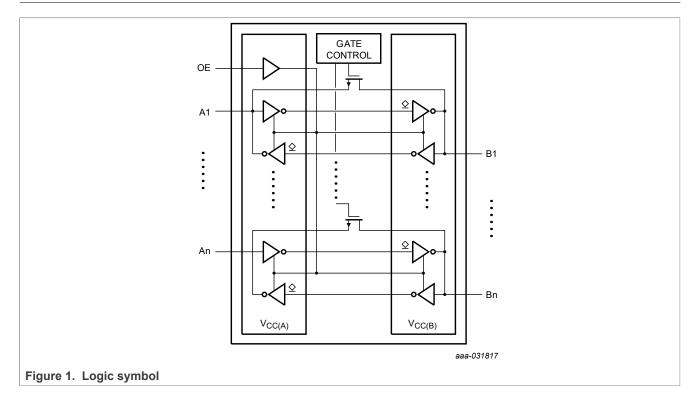
Table 1. Ordering information									
Type number	Topside	Package							
	marking	Name	Description						
NTS0308EPW	Line A: NTS0308 Line B: EPW	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1					

4.1 Ordering options

Table 2. Ordering options

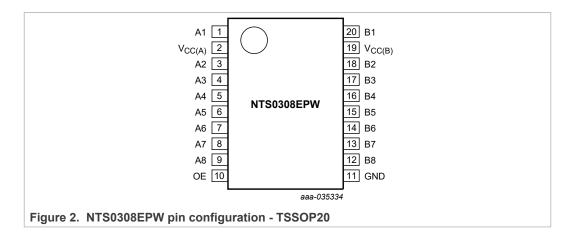
Type number	Orderable part number	Package	Packing method	Minimum order quantity	Temperature
NTS0308EPW	NTS0308EPWJ	TSSOP20	reel 13" q1/t1 *standard mark smd	2500	T_{amb} = -40 °C to +125 °C

5 Functional diagram



6 Pinning information

6.1 Pinning



6.2 Pin description

Symbol	Pin	Description
V _{CC(A)}	2	supply voltage A
A1, A2, A3, A4, A5, A6, A7, A8	1, 3, 4, 5, 6, 7, 8, 9	data input or output (referenced to $V_{CC(A)}$)
GND	11	ground (0 V)
OE	10	output enable input (active HIGH; referenced to $V_{CC(A)}$)
B8, B7, B6, B5, B4, B3, B2, B1	12, 13, 14, 15, 16, 17, 18, 20	data input or output (referenced to $V_{CC(B)}$)
V _{CC(B)}	19	supply voltage B

7 Functional description

Table 4. Function table^[1]

Supply voltage		Input	Input/output	
V _{CC(A)}	V _{CC(B)}	OE	Α	В
0.95 V to V _{CC(B)}	1.65 V to 5.5 V	L	Z	Z
0.95 V to V _{CC(B)}	1.65 V to 5.5 V	Н	input or output	output or input
GND ^[2]	GND ^[2]	X	Z	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] When either $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into power-down mode.

Limiting values 8

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC(A)}	supply voltage A			-0.5	+4.6	V
V _{CC(B)}	supply voltage B			-0.5	+6.5	V
VI	input voltage	A port and OE input	[1][2]	-0.5	+6.5	V
		B port	[1][2]	-0.5	+6.5	V
Vo	output voltage	Active mode	[1][2]			
		A or B port		-0.5	V _{CCO} + 0.5	V
		Power-down or 3-state mode	[1]			
		Fower-down or 3-state mode	-0.5	+4.6	V	
		B port		-0.5	+6.5	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
I _{OK}	output clamping current	V ₀ < 0 V		-50	-	mA
I _O	output current	$V_{O} = 0 V$ to V_{CCO}	[2]	-	±50	mA
I _{CC}	supply current	$I_{CC(A)}$ or $I_{CC(B)}$		-	100	mA
I _{GND}	ground current			-100	-	mA
T _{stg}	storage temperature			-65	+150	°C

[1] [2] The minimum input and minimum output voltage ratings may be exceeded if the input and output current ratings are observed. V_{CCO} is the supply voltage associated with the output.

9 **Recommended operating conditions**

Table 6. Recommended operating conditions^{[1][2]}

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC(A)}	supply voltage A		[2]	0.95	3.6	V
V _{CC(B)}	supply voltage B			1.65	5.5	V
V _{I_EN}	EN input voltage			-0.3	V _{CC(A)} +0.3	V
T _{amb}	ambient temperature			-40	+125	°C
TJ	junction temperature		[3]	-40	+125	°C
Δt/ΔV	input transition rise and fall rate	A or B port; push-pull driving				
		$V_{CC(A)} = 0.95 V \text{ to } 3.6 V;$ $V_{CC(B)} = 1.65 V \text{ to } 5.5 V$	[2]	-	10	ns/V
		OE input				
		$V_{CC(A)} = 0.95 V \text{ to } 3.6 V;$ $V_{CC(B)} = 1.65 V \text{ to } 5.5 V$		-	10	ns/V

The A and B sides of an unused I/O pair must be held in the same state, both at V_{CCI} or both at GND. [1]

[2] [3]

 $V_{CC(A)}$ must be less than or equal to $V_{CC(B)}$. The T_J limits shall be supported by proper thermal PCB design taking the power consumption and the thermal resistance as listed in <u>Table 7</u> into account.

10 Thermal characteristics

Table 7. Thermal resistance information						
Symbol	Rating	NTS0308EPW (TSSOP20)				
R _{θJA}	Junction to ambient	77.7 °C/W				
Ψ _{JT}	Junction to top characterization	0.3 °C/W				

11 Static characteristics

Table 8. Typical static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T_{amb} = 25 °C.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
l _l	input leakage current	OE input; V _I = 0 V to 3.6 V; V _{CC(A)} = 0.95 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V		-	-	±1	μA
I _{OZ}	OFF-state output current	A or B port; $V_O = 0$ V or V_{CCO} ; $V_{CC(A)} = 0.95$ V to 3.6 V; $V_{CC(B)} = 1.65$ V to 5.5 V	[1]	-	-	±1	μA
Cı	input capacitance	OE input; $V_{CC(A)}$ = 3.3 V; $V_{CC(B)}$ = 3.3 V		-	1	-	pF
C _{I/O}	input/output	A port		-	4	-	pF
	capacitance	B port		-	7.5	-	pF
		A or B port; $V_{CC(A)}$ = 3.3 V; $V_{CC(B)}$ = 3.3 V		-	11	-	pF

[1] V_{CCO} is the supply voltage associated with the output.

Table 9. Typical supply current

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T_{amb} = 25 °C.

V _{CC(A)}			V _{CC(B)}	V _{CC(B)}							
	1.65 V		2.5 V	2.5 V		3.3 V		5.0 V			
	I _{CC(A)}	I _{CC(B)}									
0.95 V	0.1	0.1	0.1	0.5	0.1	0.5	0.1	3	μA		
1.2 V	0.1	0.1	0.1	0.5	0.1	0.5	0.1	3	μA		
1.8 V	-	-	0.1	0.5	0.1	0.5	0.1	3	μA		
2.5 V	-	-	0.2	0.5	0.1	0.5	0.1	3	μA		
3.3 V	-	-	-	-	0.1	0.1	0.1	2	μA		

Table 10. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to	o +85 °C	-40 °C to	Unit		
			Min	Мах	Min	Max		
V _{IH}	HIGH-level	A port						
	input voltage	$V_{CC(A)} = 0.95 V$ to 1.65 V; $V_{CC(B)} = 1.65 V$ to 5.5 V	[1]	V _{CCI} - 0.2	-	V _{CCI} - 0.2	-	V
V _{IH} 		$V_{CC(A)} = 1.65 V \text{ to } 3.6 V;$ $V_{CC(B)} = 2.3 V \text{ to } 5.5 V$	[1]	V _{CCI} - 0.4	-	V _{CCI} - 0.4	-	V
		B port						
		$V_{CC(A)} = 0.95 V \text{ to } 3.6 V;$ $V_{CC(B)} = 1.65 V \text{ to } 5.5 V$	[1]	V _{CCI} - 0.4	-	V _{CCI} - 0.4	-	V
		OE input						
		$V_{CC(A)} = 0.95 V \text{ to } 3.6 V;$ $V_{CC(B)} = 1.65 V \text{ to } 5.5 V$		0.65V _{CC(A)}	-	0.65V _{CC(A)}	- \\ 0.13 \\ 0.15 \\ 0.35V _{CC(A)} \\ - \\	V
V _{IL}	LOW-level	A or B port						
	input voltage	$V_{CC(A)} = 0.95 V$ to 1.65 V; $V_{CC(B)} = 1.65 V$ to 5.5 V		-	0.13	-	0.13	V
		$V_{CC(A)} = 1.65 V \text{ to } 3.6 V;$ $V_{CC(B)} = 2.3 V \text{ to } 5.5 V$		-	0.15	-	0.15	V
		OE input						
			V					
V _{OHA}	HIGH-level output voltage	Ι _O = -20 μΑ						
		$V_{CC(B)} = 1.65 V \text{ to } 5.5 V;$ $V_{CCI} = V_{CC(B)} - 0.4 V$	[2]					
		V _{CC(A)} = 1.65 V to 3.6 V	[2]	0.8V _{CC(A)}	-	0.75V _{CC(A)}	-	V
		V _{CC(A)} = 0.95 V to 1.65 V	[2]	0.65V _{CC(A)}	-	0.62V _{CC(A)}	-	V
V _{OHB}	HIGH-level	I _O = -20 μA						
	output voltage	$\label{eq:V_CC(A)} \begin{array}{l} = 0.95 \ V \ to \ 3.6 \ V; \\ V_{CC(B)} = 1.65 \ V \ to \ 5.5 \ V; \\ V_{CCI} = V_{CC(A)} - 0.2 \ V \end{array}$	[2]	0.8V _{CC(B)}	-	0.75V _{CC(B)}	-	V
V _{OL}	LOW-level	A or B port; I _O = 1 mA	[2]					
	output voltage	$V_{\rm I} \le 0.15 \text{ V}; V_{\rm CC(A)} = 0.95 \text{ V to} \\ 3.6 \text{ V}; V_{\rm CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	0.30	-	0.30	V
I	input leakage current	OE input; V _I = 0 V to 3.6 V; V _{CC(A)} = 0.95 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V		-	±2	-	±12	μA
l _{oz}	OFF-state output current	A or B port; $V_O = 0 V$ or V_{CCO} ; $V_{CC(A)} = 0.95 V$ to 3.6 V; $V_{CC(B)} = 1.65 V$ to 5.5 V	[2]	-	±2	-	±12	μA
I _{CC}	supply current	$V_{I} = 0 V \text{ or } V_{CCI}; I_{O} = 0 A$	[1]					
		I _{CC(A)}						

Table 10. Static characteristics...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	rameter Conditions		:o +85 °C	-40 °C to	+125 °C	Unit
			Min	Max	Min	Max	
		V _{CC(A)} = 0.95 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V	-	2.4	-	15	μA
		V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V	-	2.2	-	15	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 5.5 V	-	-1	-	-8	μA
		I _{CC(B)}					
		V _{CC(A)} = 0.95 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V	-	18	-	51	μA
		V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V	-	-1	-	-5	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 5.5 V	-	18	-	46	μA
		I _{CC(A)} + I _{CC(B)}					
		V _{CC(A)} = 0.95 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V	-	14.4	-	59	μA

[1]

 V_{CCI} is the supply voltage associated with the input. V_{CCO} is the supply voltage associated with the output. [2]

12 Dynamic characteristics

Table 11. Dynamic characteristics for temperature range -40 $^{\circ}\text{C}$ to +125 $^{\circ}\text{C}^{[1]}$

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 5; for wave forms, see Figure 3 and Figure 4.

Symbol	Parameter	Conditions				Vc	C(B)			Unit
			1.8 V		3.3 V		5.0 V			
					Max	Min	Мах	Min	Max	
V _{CC(A)} =	0.95V						1	1		
t _{PHL}	HIGH to LOW propagation delay	A to B		-	20	-	11.1	-	12.3	ns
t _{PLH}	LOW to HIGH propagation delay	A to B		-	14.8	-	12.5	-	12.2	ns
t _{PHL}	HIGH to LOW propagation delay	B to A		-	9.2	-	5.2	-	5.2	ns
t _{PLH}	LOW to HIGH propagation delay	B to A		-	8.8	-	2.9	-	1.4	ns
t _{en}	enable time	OE to A; B		-	200	-	200	-	200	ns
t _{dis}	disable time	OE to A; no external load	[2]	-	100	-	100	-	100	ns
		OE to B; no external load	[2]	-	100	-	100	-	100	ns
		OE to A		-	250	-	250	-	250	ns
		OE to B		-	220	-	220	-	220	ns
t _{TLH}	LOW to HIGH	A port		6.0	15.3	2.2	15.1	1.8	11.1	ns
	output transition time	B port		6.0	17.0	4.0	14.0	4.0	20.0	ns

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Symbol	Parameter	Conditions		V _{CC(B)}						Unit
			1.8 V		3.3 V		5.0 V			
			-	Min	Мах	Min	Max	Min	Мах	
t _{THL}	HIGH to LOW	A port		0.9	18.0	0.7	9.0	0.6	9.0	ns
	output transition time	B port		1.6	22.0	2.8	10.7	3.2	14.2	ns
t _W	pulse width	data inputs		49	-	49	-	49	-	ns
f _{data}	data rate		[3]	-	20	-	20	-	20	Mbps

Table 11. Dynamic characteristics for temperature range -40 °C to +125 °C^[1]...continued Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 5; for wave forms, see Figure 3 and Figure 4.

[1]

[2] [3]

t_{en} is the same as t_{PZL} and t_{PZH}; t_{dis} is the same as t_{PLZ} and t_{PHZ}. Delay between OE going LOW and when the outputs are disabled. Assuming a maximum one-shot accelerator pulse length of 50 ns and equal time for 1 and 0 bit information.

Table 12. Dynamic characteristics for temperature range -40 °C to +125 °C ^[1]
Voltages are referenced to GND (ground = 0 V); for test circuit, see <u>Figure 5</u> ; for wave forms, see <u>Figure 3</u> and <u>Figure 4</u> .

Symbol	Parameter	Conditions				Vc	C(B)			Unit
			Ī	2.5 V		3.3 V		5.0 V		
			Min	Max	Min	Max	Min	Max		
V _{CC(A)} =	1.8 V									
t _{PHL}	HIGH to LOW propagation delay	A to B		-	5.8	-	5.9	-	7.3	ns
t _{PLH}	LOW to HIGH propagation delay	A to B		-	8.5	-	8.5	-	8.8	ns
t _{PHL}	HIGH to LOW propagation delay	B to A		-	5.5	-	5.7	-	5.9	ns
t _{PLH}	LOW to HIGH propagation delay	B to A		-	6.7	-	5.7	-	1.4	ns
t _{en}	enable time	OE to A; B		-	200	-	200	-	200	ns
t _{dis}	disable time	OE to A; no external load	[2]	-	100	-	100	-	100	ns
		OE to B; no external load	[2]	-	100	-	100	-	100	ns
		OE to A		-	250	-	250	-	250	ns
		OE to B		-	220	-	220	-	220	ns
t _{TLH}	LOW to HIGH	A port		3.2	11.9	1.2	11.7	1.1	9.5	ns
	output transition time	B port		3.3	13.5	2.7	14.5	2.7	13.5	ns
t _{THL}	HIGH to LOW	A port		1.2	7.4	1.0	7.5	1.0	16.7	ns
output transition time		B port		2.6	9.5	2.2	9.4	2.8	12.5	ns
t _W	pulse width	data inputs		49	-	49	-	49	-	ns
f _{data}	data rate		[3]	_	20	_	20	_	20	Mbps

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8-bit dual supply translating transceiver; open drain; auto direction sensing

Symbol	Parameter	Conditions		V _{CC(B)}						
				2.	5 V	3.	3 V	5.0 V		
				Min	Max	Min	Мах	Min	Мах	
t _{PHL}	HIGH to LOW propagation delay	A to B		-	4.0	-	4.2	-	4.3	ns
t _{PLH}	LOW to HIGH propagation delay	A to B		-	4.4	-	5.2	-	5.5	ns
t _{PHL}	HIGH to LOW propagation delay	B to A		-	3.8	-	4.5	-	5.4	ns
t _{PLH}	LOW to HIGH propagation delay	B to A		-	3.2	-	2.0	-	1.5	ns
t _{en}	enable time	OE to A; B		-	200	-	200	-	200	ns
t _{dis}	disable time	OE to A; no external load	[2]	-	100	-	100	-	100	ns
		OE to B; no external load	[2]	-	100	-	100	-	100	ns
		OE to A		-	220	-	220	-	220	ns
		OE to B		-	220	-	220	-	220	ns
t _{TLH} LOW to HIGH	A port		2.8	10	1.4	8.3	1.2	7.8	ns	
	output transition time	B port		3.2	10.4	2.9	15.5	2.4	16.9	ns
	HIGH to LOW	A port		1.0	7.2	1.0	6.9	1.0	6.7	ns
	output transition time	B port		2.2	9.8	2.4	8.4	2.6	8.3	ns
t _W	pulse width	data inputs		49	-	49	-	49	-	ns
f _{data}	data rate		[3]	-	20	-	20	-	20	Mbps
V _{CC(A)} =	3.3 V	1			-			1	1	
t _{PHL}	HIGH to LOW propagation delay	A to B		-	-	-	3.0	-	3.9	ns
t _{PLH}	LOW to HIGH propagation delay	A to B		-	-	-	5.3	-	5.5	ns
t _{PHL}	HIGH to LOW propagation delay	B to A		-	-	-	3.2	-	4.2	ns
t _{PLH}	LOW to HIGH propagation delay	B to A		-	-	-	3.2	-	3.3	ns
t _{en}	enable time	OE to A; B		-	-	-	200	-	200	ns
t _{dis}	disable time	OE to A; no external load	[2]	-	-	-	100	-	100	ns
		OE to B; no external load	[2]	-	-	-	100	-	100	ns
		OE to A		-	-	-	280	-	280	ns
		OE to B		-	-	-	220	-	220	ns
t _{TLH}	LOW to HIGH	A port		-	-	1.2	13.1	1.1	7.4	ns
	output transition time	B port		-	-	2.5	14.2	2.1	16.0	ns

Table 12. Dynamic characteristics for temperature range -40 °C to +125 °C^[1]...continued Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 5; for wave forms, see Figure 3 and Figure 4.

Product data sheet

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Table 12. Dynamic characteristics for temperature range -40 °C to +125 °C ^[1] continued
Voltages are referenced to GND (ground = $0 V$); for test circuit, see Figure 5; for wave forms, see Figure 3 and Figure 4.

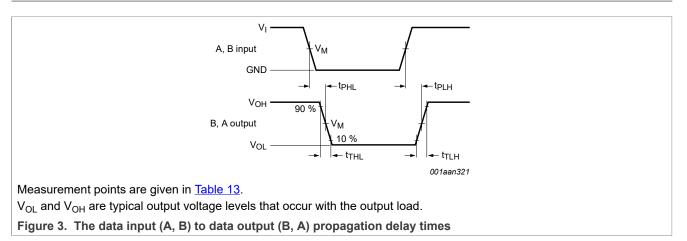
Symbol	Parameter Conditions		V _{CC(B)}							
						3.3 V		5.0 V		
				Min	Мах	Min	Мах	Min	Мах	
t _{THL}	HIGH to LOW output transition time	A port		-	-	1.0	6.8	1.0	6.3	ns
		B port		-	-	2.3	9.3	2.4	9.5	ns
t _{vv}	pulse width	data inputs		-	-	49	-	49	-	ns
f _{data}	data rate		[3]	-	-	-	20	-	20	Mbps

 t_{en} is the same as t_{PZL} and $t_{PZH}; t_{dis}$ is the same as t_{PLZ} and $t_{PHZ}.$ Delay between OE going LOW and when the outputs are disabled. [1]

[2] [3]

Assuming a maximum one-shot accelerator pulse length of 50 ns and equal time for 1 and 0 bit information.

13 Waveforms





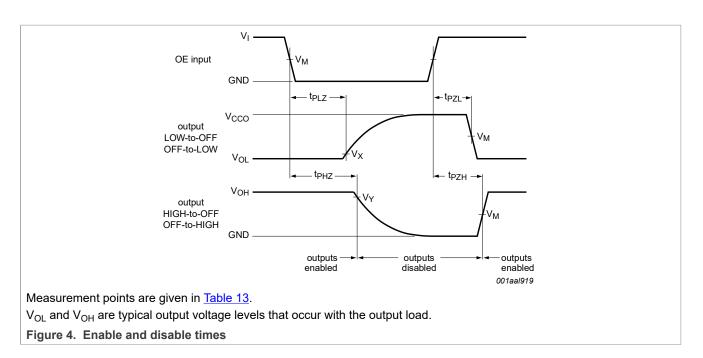


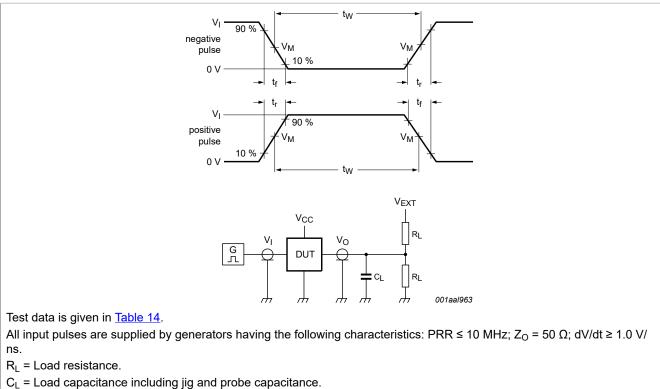
Table 13. Measurement points^{[1][2]}

Supply voltage	Input	Output	Output					
V _{cco}	V _M	V _M	V _X	V _Y				
0.95 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.1 V	V _{OH} - 0.1 V				
1.8 V ± 0.15 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.15 V	V _{OH} - 0.15 V				
2.5 V ± 0.2 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.15 V	V _{OH} - 0.15 V				
3.3 V ± 0.3 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.3 V	V _{OH} - 0.3 V				
5.0 V ± 0.5 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.3 V	V _{OH} - 0.3 V				

 V_{CCI} is the supply voltage associated with the input. V_{CCO} is the supply voltage associated with the output. [1]

[2]





 V_{EXT} = External voltage for measuring switching times.

Figure 5. Test circuit for measuring switching times

Supply voltage		Input	nput		Load		V _{EXT}		
V _{CC(A)}	V _{CC(B)}	V _I ^[1]	Δt/ΔV	CL	R _L ^[2]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ} ^[3]	
0.95 V to 3.6 V	1.65 V to 5.5 V	V _{CCI}	≤ 1.0 ns/V	15 pF	50 kΩ, 1 MΩ	open	open	2V _{CCO}	

[1] V_{CCI} is the supply voltage associated with the input.

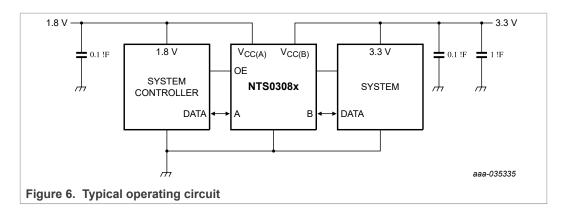
[2] For measuring data rate, pulse width, propagation delay and output rise and fall measurements, $R_L = 1 M\Omega$. For measuring enable and disable times, $R_L = 50 k\Omega$.

 $[3] \qquad V_{CCO} \text{ is the supply voltage associated with the output.}$

14 Application information

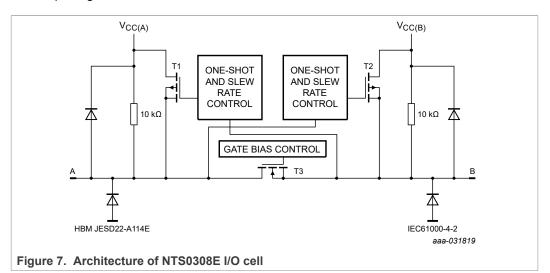
14.1 Applications

Voltage level-translation applications. The NTS0308E can be used in point-to-point applications to interface between devices or systems operating at different supply voltages. The device is primarily targeted at I^2C or 4-wire which use open-drain drivers. It may also be used in applications where push-pull drivers are connected to the ports, however the NTB010x or the newer lower voltage NTB030x series of devices are more suitable.



14.2 Architecture

The architecture of the NTS0308E is shown in <u>Figure 7</u>. The device does not require an extra input signal to control the direction of data flow from A to B or B to A.



The NTS0308E is a "switch" type voltage translator using two key circuits to enable voltage translation:

- 1. A pass-gate transistor (N-channel) that ties the ports together.
- 2. An output edge-rate accelerator that detects and accelerates rising edges on the I/O pins.

The gate bias voltage of the pass gate transistor (T3) is set at approximately one threshold voltage above the V_{CC} level of the low-voltage side. During a LOW-to-HIGH transition, the output one-shot accelerates the output transition by switching on the PMOS transistors (T1, T2). It bypasses the 10 k Ω pull-up resistors and increases the current drive capability. The one-shot is activated once the input transition reaches approximately V_{CCI}/2; it is deactivated approximately 50 ns after the output reaches V_{CCO}/2. During the acceleration time, the driver output resistance is between approximately 50 Ω and 70 Ω . To avoid signal contention and minimize dynamic I_{CC}, the user should wait for the one-shot circuit to turn-off before applying a signal in the opposite direction. Pull-up resistors are included in the device for DC current sourcing capability.

14.3 Input driver requirements

As the NTS0308E is a switch type translator, properties of the input driver directly affect the output signal. The external open-drain or push-pull driver applied to an I/O determines the static current sinking capability of the system. The max data rate, HIGH-to-LOW output transition time (t_{THL}), and propagation delay (t_{PHL}), are dependent upon the output impedance and edge-rate of the external driver. The limits provided for these parameters in the data sheet assume a driver with output impedance below 50 Ω is used.

14.4 Output load considerations

The maximum lumped capacitive load that can be driven is dependent upon the one-shot pulse duration. In cases with very heavy capacitive loading, there is a risk that the output does not reach the positive rail within the one-shot pulse duration. The NTS0308E has a longer one-shot pulse for driving larger capacitive loads.

To avoid excessive capacitive loading and to ensure correct triggering of the one-shot, use short trace lengths and low capacitance connectors on NTS0308E PCB layouts. The length of the PCB trace should be such that the round-trip delay of any reflection is within the one-shot pulse duration (approximately 50 ns). It ensures low impedance termination and avoids output signal oscillations and one-shot retriggering.

14.5 Output single shot slew rate control

Integrated slew-rate control and timed increase of the one-shot driver output current reduce EMI. An additional comparator circuit on the V_{OUT} side starts to reduce the one-shot driver current when V_{OUT} > $0.65V_{OUT}$ with a slight delay, so it can safely drive the output voltage to a safe high-level while at the same time reducing the driver strength early enough to reduce overshoots and ringing.

14.6 Power-up

During operation, $V_{CC(A)}$ must never be higher than $V_{CC(B)}$. However, during power-up, $V_{CC(A)} \ge V_{CC(B)}$ does not damage the device, so either power supply can be ramped up first. There is no special power-up sequencing required. The NTS0308E includes circuitry that disables all output ports when either $V_{CC(A)}$ or $V_{CC(B)}$ is switched off.

14.7 Enable and disable

An output enable input (OE) is used to disable the device. Setting OE = LOW causes all I/Os to assume the high-impedance OFF-state. The disable time (t_{dis} with no external load) indicates the delay between when OE goes LOW and when outputs actually become disabled. The enable time (t_{en}) indicates the amount of time the user must allow for one-shot circuitry to become operational after OE is taken HIGH. To ensure the high-impedance OFF-state during power-up or power-down, pin OE should be tied to GND through a pull-down resistor. The current-sourcing capability of the driver determines the minimum value of the resistor.

14.8 Pull-up or pull-down resistors on I/Os lines

The A port I/O has an internal 10 k Ω pull-up resistor to V_{CC(A)}. The B port I/O has an internal 10 k Ω pull-up resistor to V_{CC(B)}. If a smaller value of pull-up resistor is required,

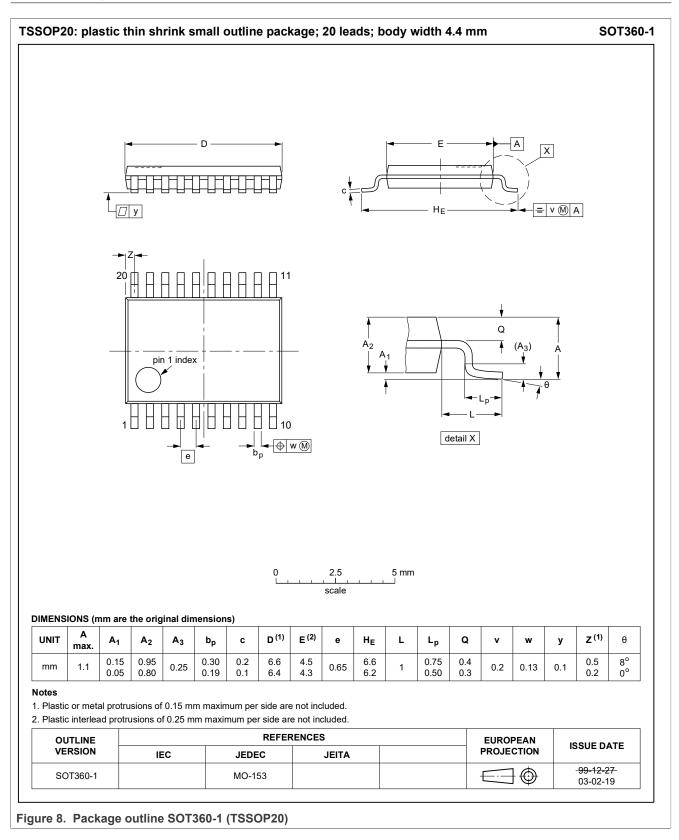
add an external resistor in parallel to the internal 10 k Ω . This pull-up resistor affects the V_{OL} level. When OE goes LOW, the internal pull-ups of the NTS0308E are disabled.

14.9 ESD protection on I/Os lines

The NTS0308E contains rail to rail ESD protection structures connecting the A and B I/ O to their respective supply. As a consequence, if a supply pin is pulled LOW, the related I/Os are pulled low too through the upper ESD protection diode and the 10 k Ω pull-up resistor. Additionally, besides the normal HBM and CDM ESD protection features on both A and B Port I/O the B Port I/O features integrated ESD protection to IEC 61000-4-2 Class 4 system ESD level of 8kV contact for when users plug cameras, games, and other items into their USB or video ports in real-world ESD stress applications.

Product data sheet

15 Package outline



NTS0308E Product data sheet

8-bit dual supply translating transceiver; open drain; auto direction sensing

16 Soldering

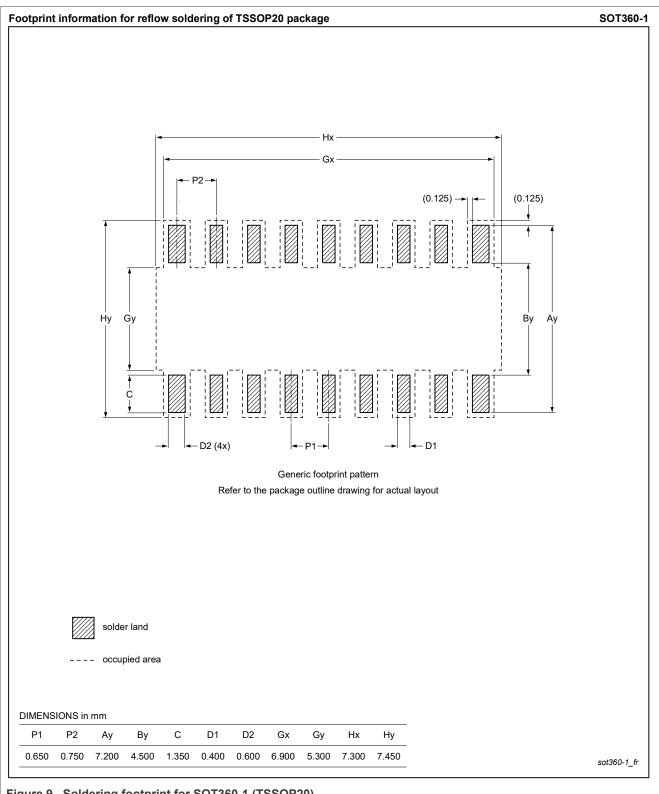


Figure 9. Soldering footprint for SOT360-1 (TSSOP20)

17 Abbreviations

Table 15. Abbre	viations
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
GPIO	General Purpose Input Output
НВМ	Human Body Model
l ² C	Inter-Integrated Circuit
IEC	International Electrotechnical Commission
ММ	Machine Model
РСВ	Printed-Circuit Board
PMOS	Positive Metal Oxide Semiconductor
SMBus	System Management Bus
UART	Universal Asynchronous Receiver Transmitter

18 Revision history

Table 16. Revision history

Document ID Release date Data sheet status		Data sheet status	Change notice	Supersedes					
NTS0308E v.1.1 20210413 Product data sheet		Product data sheet	2021030081	NTS0308E v.1.0					
Modifications:	Modifications: • <u>Table 6</u> : Corrected T _J max from +85 °C to +125 °C.								
NTS0308E v.1.0 20200609 Product data sheet			-	-					

19 Legal information

19.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

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NTS0308E

8-bit dual supply translating transceiver; open drain; auto direction sensing

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